

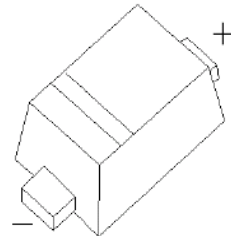


RB521S-30 Schottky barrier Diode



FEATURE

- Small surface mounting type
- Low reverse current and low forward voltage
- High reliability



MARKING: C

SOD-523

Maximum Ratings and Electrical Characteristics, Single Diode @Ta=25°C

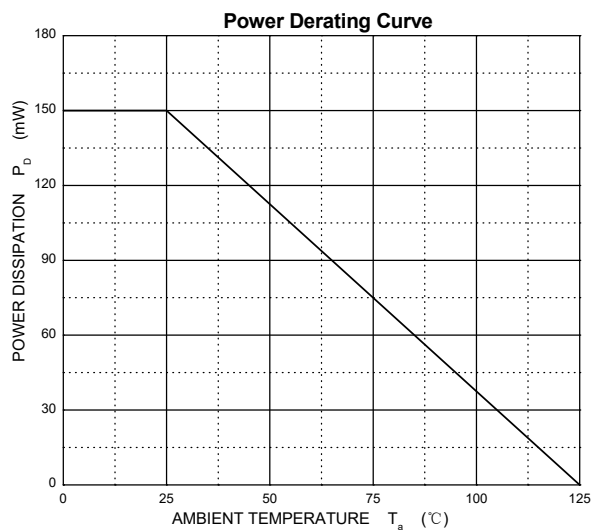
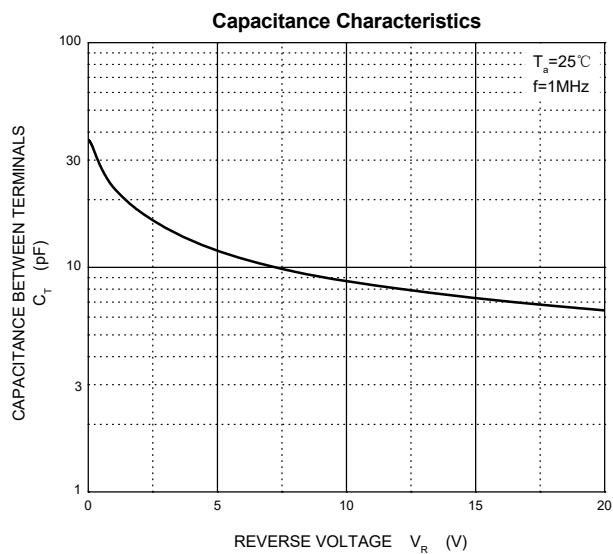
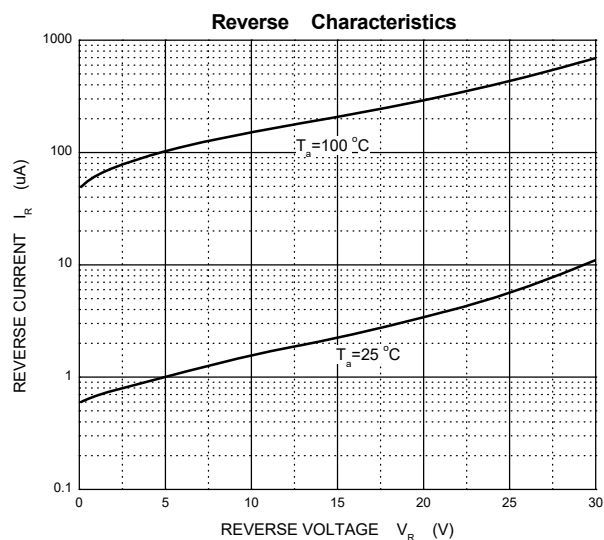
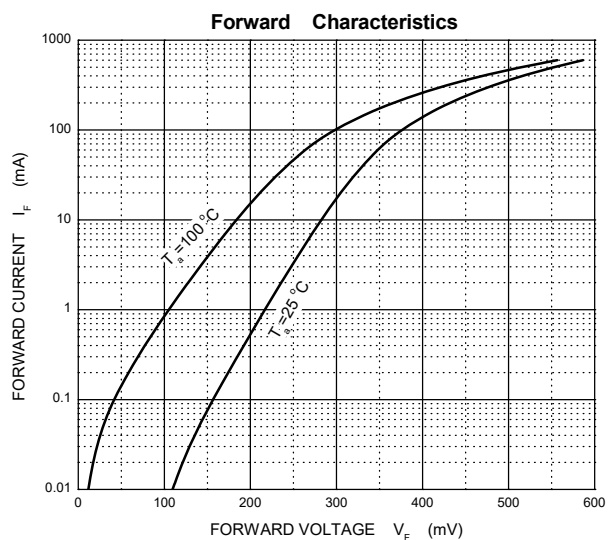
Parameter	Symbol	Limit	Unit
DC reverse voltage	V_R	30	V
Mean rectifying current	I_O	200	mA
Non-repetitive Peak forward surge current @ t=8.3ms	I_{FSM}	1	A
Power dissipation	P_D	150	mW
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	667	°C/W
Operating Junction Temperature Range	T_j	-40 ~ +125	°C
Storage Temperature Range	T_{stg}	-55 ~ +150	°C

Electrical Ratings @Ta=25°C

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Forward voltage	V_{F1}			0.35	V	$I_F=10mA$
	V_{F2}			0.6	V	$I_F=200mA$
Reverse current	I_R			30	μA	$V_R=10V$



Typical Characteristics

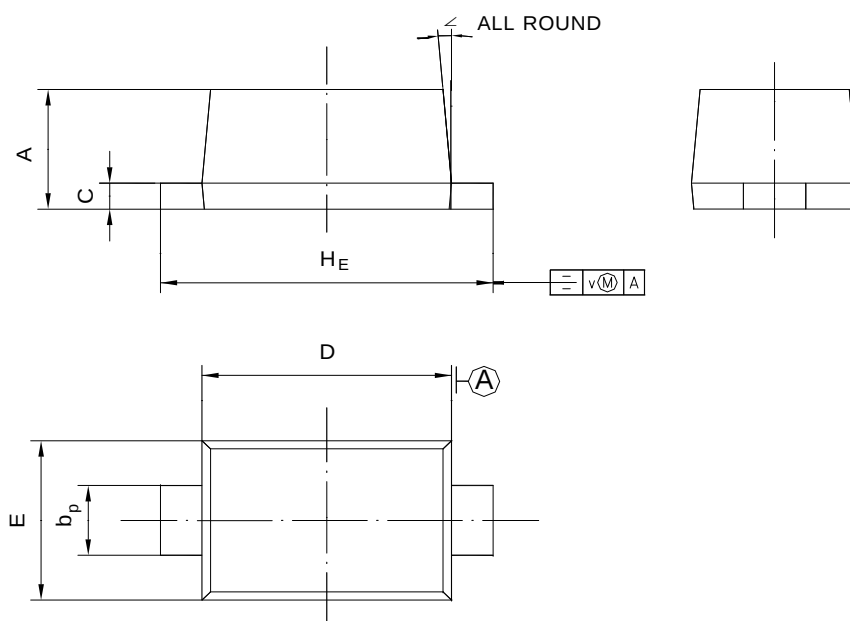




PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-523



UNIT	A	b _p	C	D	E	H _E	V	∠
mm	0.68 0.58	0.4 0.3	0.135 0.100	1.25 1.15	0.85 0.75	1.7 1.5	0.1	5°